



### **DESD1CANFD24VWQ**

#### CAN BUS FD ESD PROTECTION DIODE

### **Product Summary**

| V <sub>BR</sub> (Min) | IPP (Max) | Ст (Тур) |
|-----------------------|-----------|----------|
| 25.5V                 | 2.6A      | 5.2pF    |

## **Description and Applications**

This part is a next generation ESD and surge protection device packaged in a small footprint surface-mount package. It is qualified to AEC-Q101, supported by a PPAP and is designed to protect two data lines of the controller area network (CAN) in an automotive.

- CAN / CAN-FD
- Low and high-speed CAN
- Flex rays

SOT323



Top View

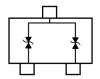
#### **Features**

- 110W Peak Power Dissipation per Line (8/20µs Waveform)
- Provides ESD Protection per IEC 61000-4-2 Standard:
   Air ±23kV, Contact ±23kV
- 2 Channels of ESD Protection
- Low Channel Input Capacitance 5.2pF for High Signal Integrity of CANFD Data Raters
- 175°C T<sub>J</sub> Rated for High-Temperature, Mission-Critical Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES DESD1CANFD24VWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Package: SOT323
- Package Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208@3
- Weight: 0.009 grams (Approximate)



**Device Schematic** 

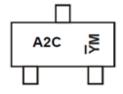
## Ordering Information (Note 4)

| Part Number       | Dackago | Marking   | Marking Reel Size (inches) | Tape Width (mm)     | Pac   | cking       |
|-------------------|---------|-----------|----------------------------|---------------------|-------|-------------|
| Fait Number       | Package | wai Kiliy |                            | rape widin (ililii) | Qty.  | Carrier     |
| DESD1CANFD24VWQ-7 | SOT323  | A2C       | 7                          | 8                   | 3,000 | Tape & Reel |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# Marking Information



A2C = Product Type Marking Code YM = Date Code Marking Y = Year (ex: K = 2023) M = Month (ex: 3 = March)

Date Code Key

| Year  | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 | 2031 | 2032 | 2033 | 2034 |
|-------|------|------|------|------|------|------|------|------|------|------|------|------|
| Code  | K    | L    | М    | N    | 0    | Р    | R    | S    | T    | U    | V    | W    |
|       |      |      |      |      |      |      |      |      |      |      |      |      |
| Month | Jan  | Feb  | Mar  | Apr  | May  | Jun  | Jul  | Aug  | Sep  | Oct  | Nov  | Dec  |



## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                     | Symbol       | Value | Unit | Conditions             |
|------------------------------------|--------------|-------|------|------------------------|
| Peak Pulse Power Dissipation       | Ppp          | 110   | W    | 8/20µs, per Figure 1   |
| Peak Pulse Current                 | Ірр          | 2.6   | Α    | 8/20µs, per Figure 1   |
| ESD Protection – Contact Discharge | VESD_Contact | ±23   | kV   | IEC 61000-4-2 Standard |
| ESD Protection – Air Discharge     | VESD_Air     | ±23   | kV   | IEC 61000-4-2 Standard |

### **Thermal Characteristics**

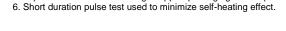
| Characteristic                                   | Symbol                            | Value       | Unit |
|--|-----------------------------------|-------------|------|
| Package Power Dissipation (Note 5)               | PD                                | 300         | mW   |
| Thermal Resistance, Junction to Ambient (Note 5) | RθJA                              | 417         | °C/W |
| Operating and Storage Temperature Range          | T <sub>J</sub> , T <sub>STG</sub> | -65 to +175 | °C   |

### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic                        | Symbol                          | Min  | Тур | Max  | Unit | Test Conditions                             |
|---------------------------------------|---------------------------------|------|-----|------|------|---|
| Reverse Standoff Voltage              | VRWM                            | _    | _   | 24   | V    | _   |
| Channel Leakage Current (Note 6)      | lкм                             | _    | 1   | 50   | nA   | V <sub>RWM</sub> = 24V                      |
| Clamping Voltage, Positive Transients | VcL                             | _    | 33  | 42   | V    | I <sub>PP</sub> = 1A, tp = 8/20μs, Figure 1 |
| Breakdown Voltage                     | VBR                             | 25.5 | 30  | 35.5 | V    | I <sub>R</sub> = 10mA                       |
| Diode Capacitance Matching            | Δ Cτ / Cτ                       | _    | 0.5 | _    | %    | V <sub>R</sub> = ±2.5V, f = 1MHz            |
| Channel Innut Canacitance             | Ст                              | _    | 5.2 | 6    | pF   | V <sub>R</sub> = ±2.5V, f = 1MHz            |
| Channel Input Capacitance             | CI                              | _    | _   | 6    | ρг   |   |
| ABS Parasitic Capacitance Matching    | Δ ((CT_Ch1-CT_Ch2)<br>/ CT Max) | _    | _   | 2    | %    | V <sub>R</sub> = 5V, f = 1MHz               |
| (Channel 1 – Channel 2)               | Δ (CT_Ch1-CT_Ch2)               | _    | _   | 0.12 | pF   |   |

Notes:

<sup>5.</sup> Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



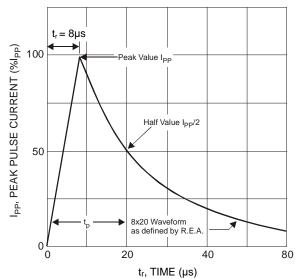


Figure 1. Pulse Waveform

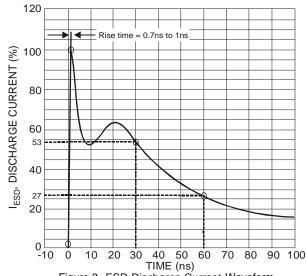
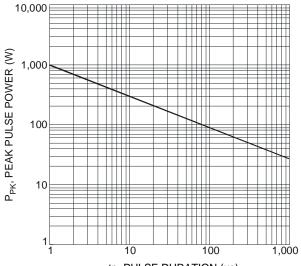


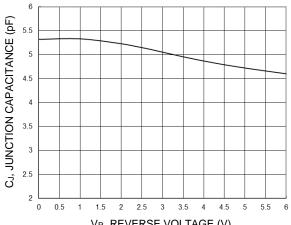
Figure 2. ESD Discharge Current Waveform IEC 61000-4-2 (330Ω/150pF)



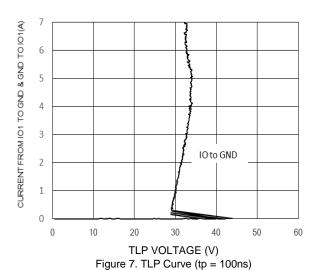


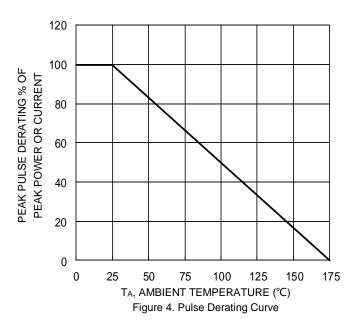


tp, PULSE DURATION (μs) Figure 3. Peak Pulse Power vs. Pulse Duration



V<sub>R</sub>, REVERSE VOLTAGE (V) Figure 5. Typical Junction Capacitance





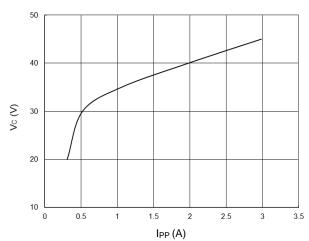


Figure 6. Typical Peak Clamping Voltage Vc vs.

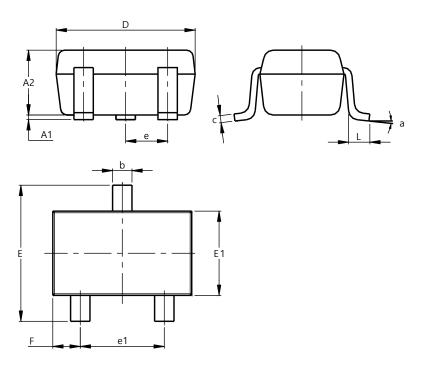
Peak Pulse Current IPP



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT323**

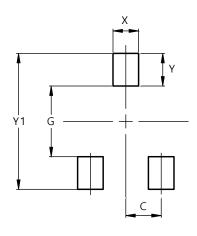


| SOT323 |                      |           |       |  |  |  |  |
|--------|----------------------|-----------|-------|--|--|--|--|
| Dim    | Min                  | Max       | Тур   |  |  |  |  |
| A1     | 0.00                 | 0.10      | 0.05  |  |  |  |  |
| A2     | 0.90                 | 1.00      | 0.95  |  |  |  |  |
| b      | 0.25                 | 0.40      | 0.30  |  |  |  |  |
| C      | 0.10                 | 0.18      | 0.11  |  |  |  |  |
| D      | 1.80                 | 2.20      | 2.15  |  |  |  |  |
| Е      | 2.00                 | 2.20      | 2.10  |  |  |  |  |
| E1     | 1.15                 | 1.35      | 1.30  |  |  |  |  |
| е      | C                    | 0.650 BSC |       |  |  |  |  |
| e1     | 1.20                 | 1.40      | 1.30  |  |  |  |  |
| F      | 0.375                | 0.475     | 0.425 |  |  |  |  |
| L      | 0.25                 | 0.40      | 0.30  |  |  |  |  |
| а      | 0°                   | 8°        |       |  |  |  |  |
| All    | All Dimensions in mm |           |       |  |  |  |  |

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT323**



| Dimensions | Value<br>(in mm) |
|------------|------------------|
| С          | 0.650            |
| G          | 1.300            |
| Х          | 0.470            |
| Υ          | 0.600            |
| Y1         | 2 500            |



#### **IMPORTANT NOTICE**

- 1. DIODES INCORPORATED (Diodes) AND ITS SUBSIDIARIES MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).
- 2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes' products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes' products. Diodes' products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of Diodes' products for their intended applications, (c) ensuring their applications, which incorporate Diodes' products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.
- 3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.
- 4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.
- 5. Diodes' products are provided subject to Diodes' Standard Terms and Conditions of Sale (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
- 6. Diodes' products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes' products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.
- 7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.
- 8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.
- 9. This Notice may be periodically updated with the most recent version available at <a href="https://www.diodes.com/about/company/terms-and-conditions/important-notice">https://www.diodes.com/about/company/terms-and-conditions/important-notice</a>

The Diodes logo is a registered trademark of Diodes Incorporated in the United States and other countries. All other trademarks are the property of their respective owners.

© 2023 Diodes Incorporated. All Rights Reserved.

www.diodes.com